

AM3163 – Filter Bank

Digitally Tunable 2 to 18 GHz Bandpass



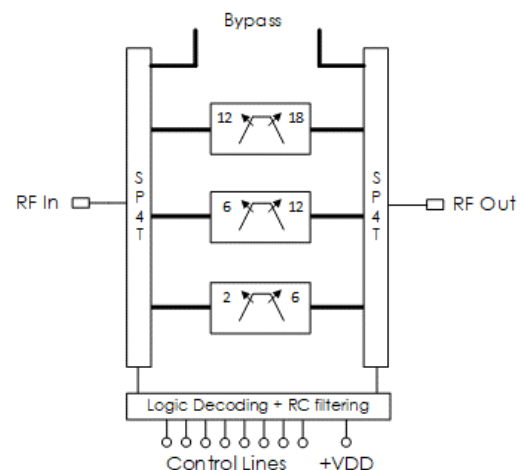
Description

AM3163 is a digitally tunable bandpass filter bank covering the 2 GHz to 18 GHz frequency range. The device provides three separate tunable filter bands with 16 low-pass and 16 high-pass tuning states for independent control of both the center frequency and bandwidth. The filter bank has integrated switches with a 20 GHz bypass path. AM3163 is packaged in a 6mm QFN package and operates over the -40C to +85C temperature range. Its small size, weight, and power consumption make it an attractive choice for demanding applications requiring low SWaP components.

Features

- 2 to 18 GHz Digitally Tunable Bandpass Filter Bank
- Internal SP4T Switches
- Integrated Control Line Filtering
- Independent LP and HP control
- +3.3V to +5.0V Supply
- 8 dB typical Insertion Loss
- 20 GHz Filter Bypass Path
- +39 dBm Input IP3
- +26 dBm Input P1dB
- -40C to +85C Operation
- 6mm QFN

Functional Diagram



Characteristic Performance

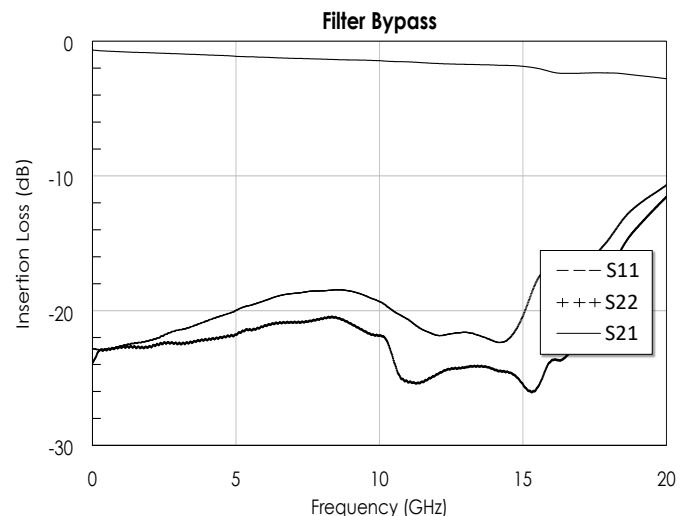
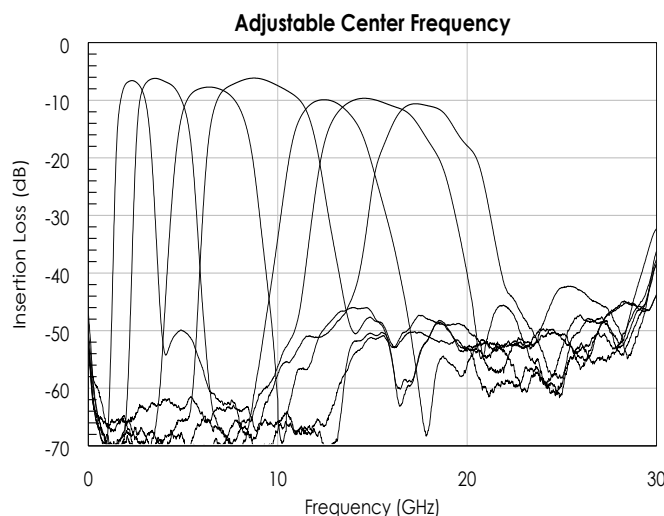


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Revision History

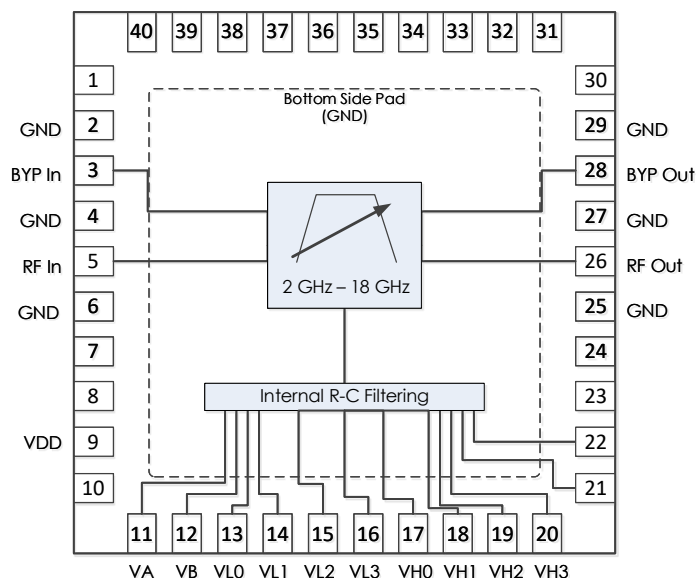
Date	Revision Number	Notes
August 26, 2020	1	Initial Release
May 4, 2021	2	Updated diagrams
March 11, 2024	2.1	Corrected Pin 16 description in Pin Layout

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Pin Layout and Definitions

Note: All Non-Assigned Pins are GND



Pin Number	Pin Name	Pin Function
1-2	GND	Ground – Common
3	BYP In	Filter Bypass Input Side – 50 Ohms – DC Coupled, External DC Blocking Cap Required
4	GND	Ground – Common
5	RF In	RF Input – 50 Ohms – DC Coupled, External DC Blocking Cap Required
6-8	GND	Ground – Common
9	VDD	DC Power Input
10	GND	Ground – Common
11	VA	Switch Control A
12	VB	Switch Control B
13	VL0	Low Pass Filter Control Bit 0 (LSB)
14	VL1	Low Pass Filter Control Bit 1
15	VL2	Low Pass Filter Control Bit 2
16	VL3	Low Pass Filter Control Bit 3 (MSB)
17	VH0	High Pass Filter Control Bit 0 (LSB)
18	VH1	High Pass Filter Control Bit 1
19	VH2	High Pass Filter Control Bit 2
20	VH3	High Pass Filter Control Bit 3 (MSB)
21-25	GND	Ground – Common
26	RF Out	RF Output – 50 Ohms – DC Coupled, External DC Blocking Cap Required
27	GND	Ground – Common
28	BYP Out	Filter Bypass Output Side – 50 Ohms – DC Coupled, External DC Blocking Cap Required
29-40	GND	Ground – Common
Bottom Pad	GND	Ground – Common

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Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Supply Voltage	-0.3 V	+8.0 V
RF Input Power		+27 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 1	



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V	+5.0 V	+5.2 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

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DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
DC Supply Voltage		+3.0 V	+5.0 V	+5.2 V
DC Supply Current	VDD = +5.0 V		6 mA	
Power Dissipated	VDD = +5.0 V		30 mW	
Logic Level Low		-0.1 V		+0.5 V
Logic Level High		+2.0 V		+VDD V

RF Performance

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		2 GHz		18 GHz
Insertion Loss	f = 2 GHz		-7.1 dB	
	f = 4 GHz		-6.3 dB	
	f = 6 GHz		-7.7 dB	
	f = 9 GHz		-6.2 dB	
	f = 12 GHz		-7.2 dB	
	f = 15 GHz		-9.8 dB	
	f = 18 GHz		-11 dB	
Return Loss			-12 dB	
Input IP3	VDD = +5.0 V		+39 dBm	
Input P1dB	VDD = +5.0 V		+26 dBm	

Timing Characteristics

Parameter	Minimum	Typical	Maximum
Switching Speed		40 ns	
Band Tuning Speed		400 ns	

State Table

VA	VB	Filter Band
Low	Low	Bypass State
High	High	Band 1 – 2.0 to 6.0 GHz
Low	High	Band 2 – 6.0 to 12 GHz
High	Low	Band 3 – 12 to 18 GHz

Notes:

1. OIP3 was measured at 10 MHz input tone spacing

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State Table (continued)

High Pass Filter Typical Cutoff Frequencies (GHz)

VH3	VH2	VH1	VH0	Band 1	Band 2	Band 3
Low	Low	Low	Low	1.7	5.1	11
Low	Low	Low	High	1.8	5.2	11.1
Low	Low	High	Low	1.85	5.3	11.2
Low	Low	High	High	1.9	5.3	11.4
Low	High	Low	Low	1.92	5.4	11.4
Low	High	Low	High	1.96	5.5	11.5
Low	High	High	Low	2	5.7	11.7
Low	High	High	High	2.1	5.9	12
High	Low	Low	Low	2.4	5.8	11.8
High	Low	Low	High	2.44	6	12
High	Low	High	Low	2.5	6.3	12.3
High	Low	High	High	2.6	6.5	12.7
High	High	Low	Low	2.8	6.8	12.8
High	High	Low	High	3	7.3	13.4
High	High	High	Low	3.3	8.1	14.2
High	High	High	High	3.9	9.1	15.8

Low Pass Filter Typical Cutoff Frequencies (GHz)

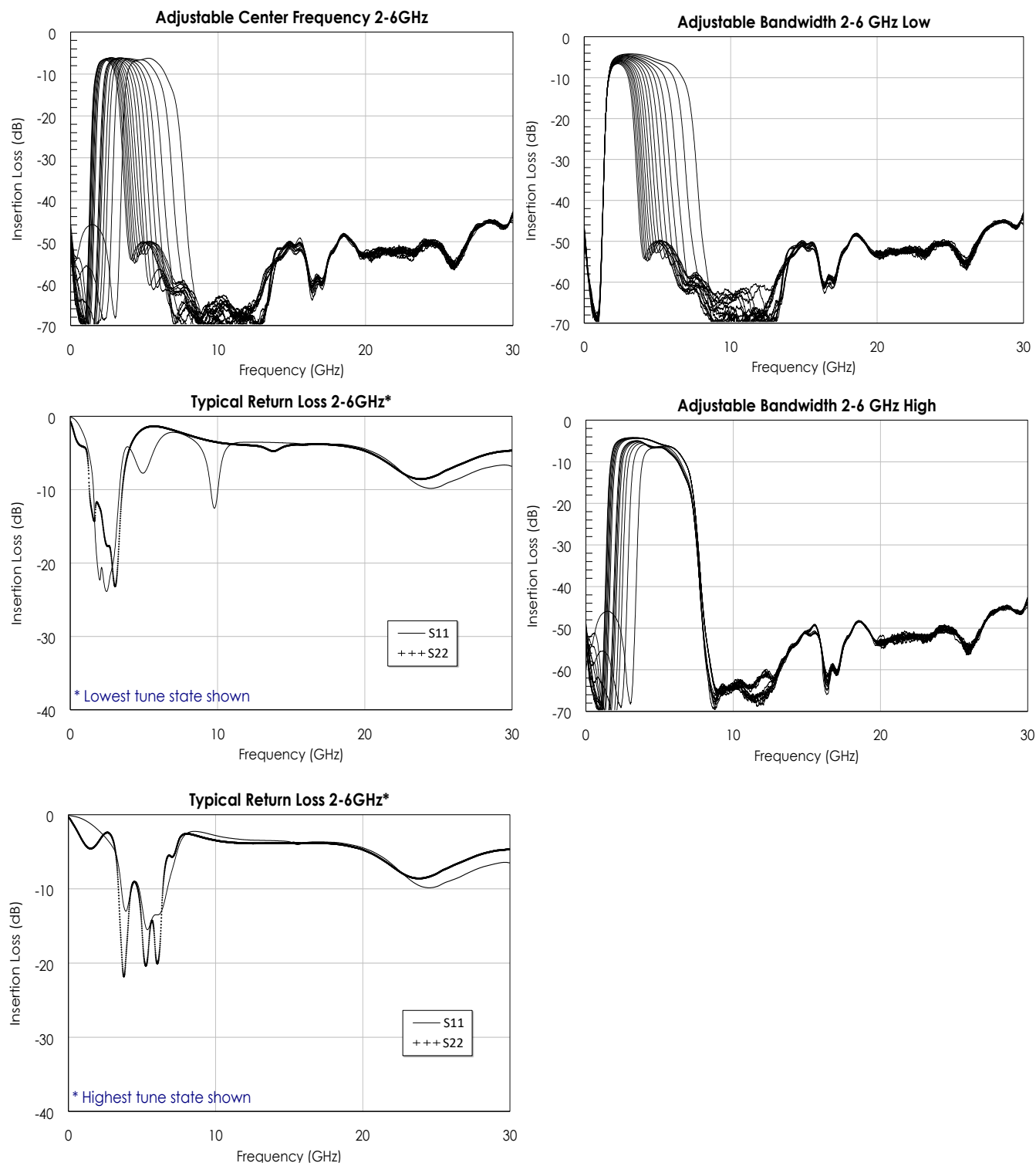
VL3	VL2	VL1	VL0	Band 1	Band 2	Band 3
Low	Low	Low	Low	2.9	7.8	13.8
Low	Low	Low	High	3	8	13.9
Low	Low	High	Low	3.1	8.1	14.1
Low	Low	High	High	3.2	8.3	14.4
Low	High	Low	Low	3.3	8.6	14.5
Low	High	Low	High	3.4	8.8	14.9
Low	High	High	Low	3.5	9	15.2
Low	High	High	High	3.7	9.1	15.4
High	Low	Low	Low	3.9	9.2	15.7
High	Low	Low	High	4.1	9.5	16
High	Low	High	Low	4.3	9.8	16.2
High	Low	High	High	4.5	10.1	16.6
High	High	Low	Low	4.8	10.6	16.7
High	High	Low	High	5.1	11	17.2
High	High	High	Low	5.6	11.6	18
High	High	High	High	6.3	12.3	19.6

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Typical Performance



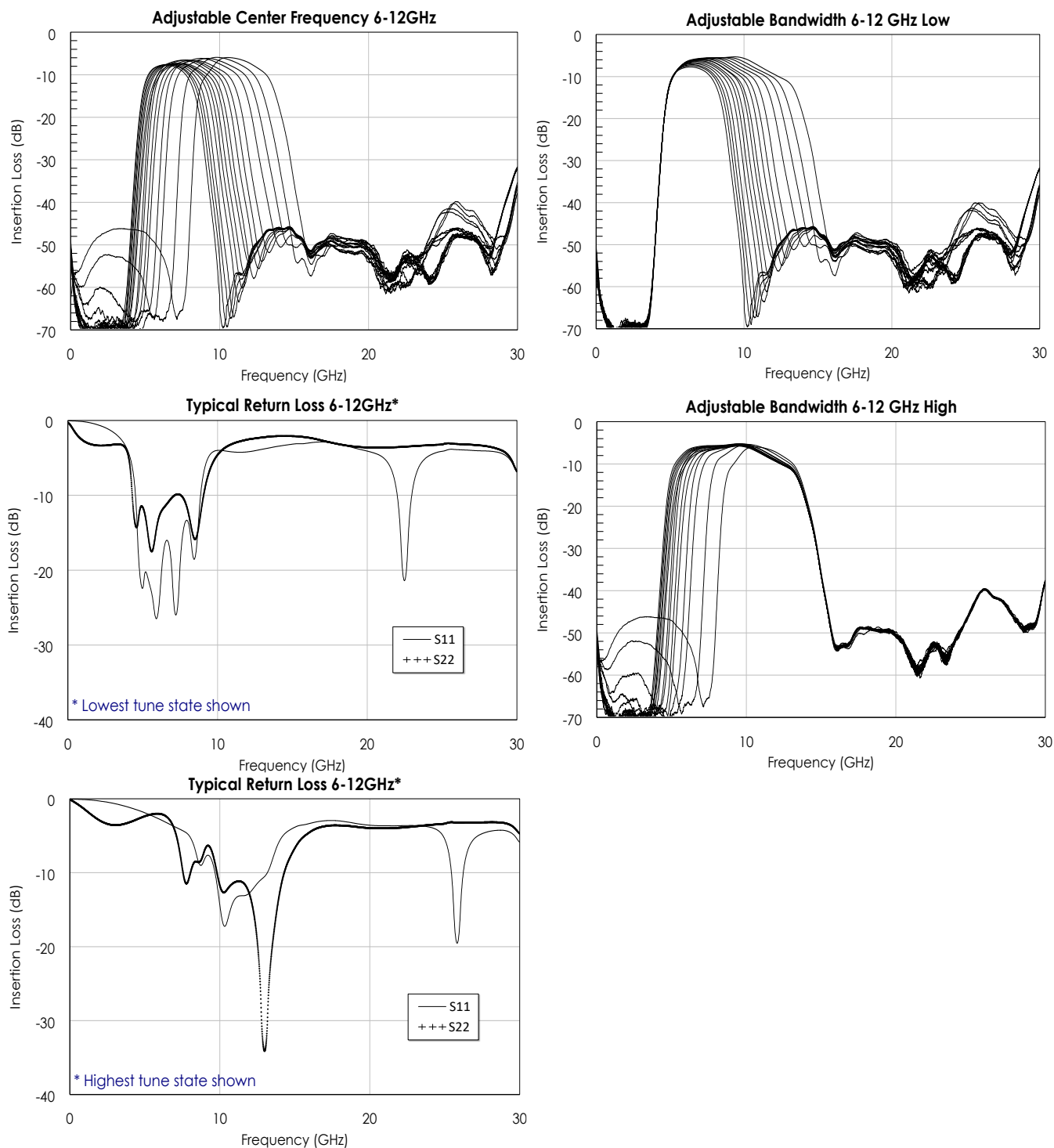
* Typical values shown for lowest tuned frequency (control bits 0000) or highest tuned frequency (control bits 1111)

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Typical Performance (continued)



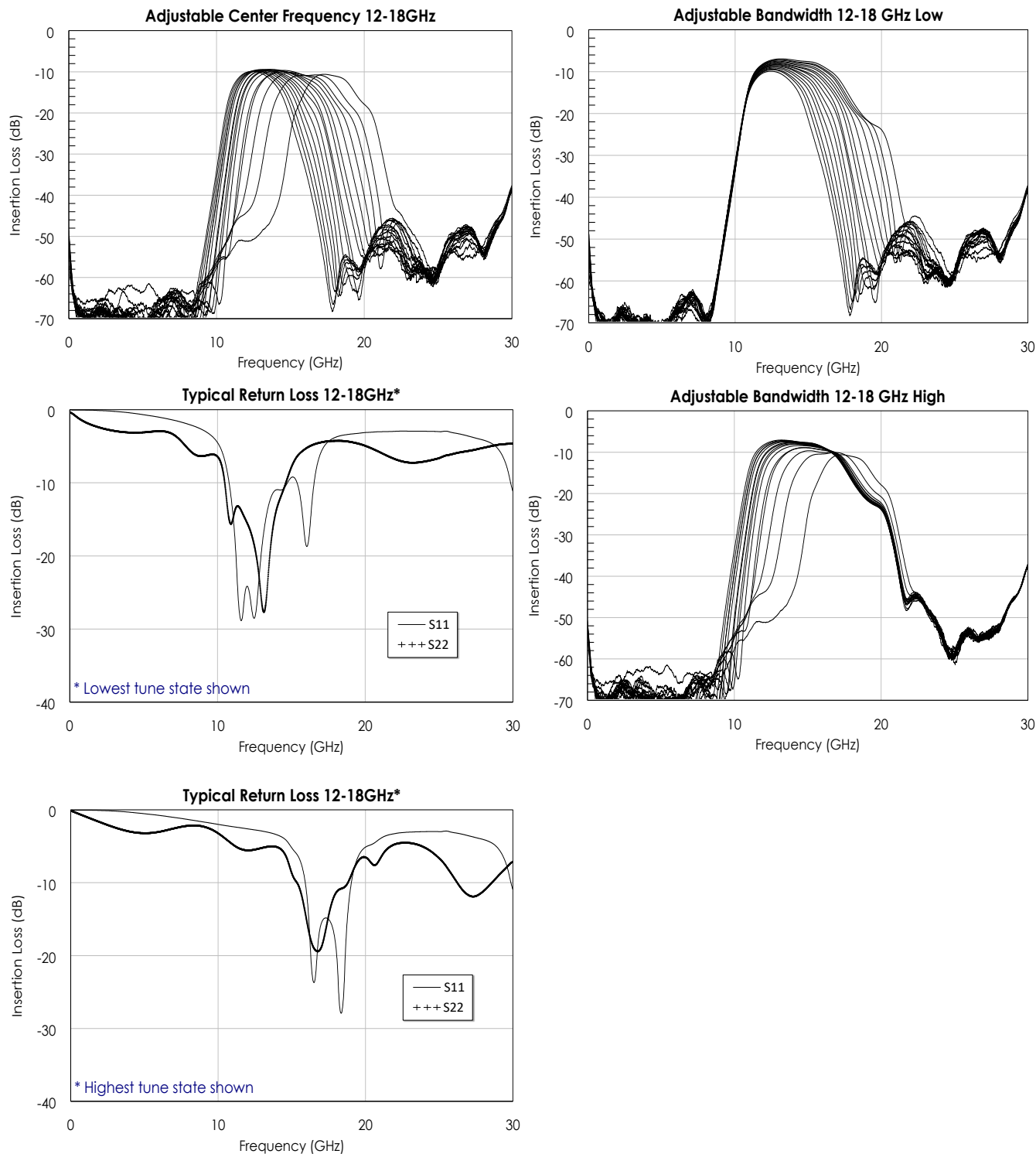
* Typical values shown for lowest tuned frequency (control bits 0000) or highest tuned frequency (control bits 1111)

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Typical Performance (continued)

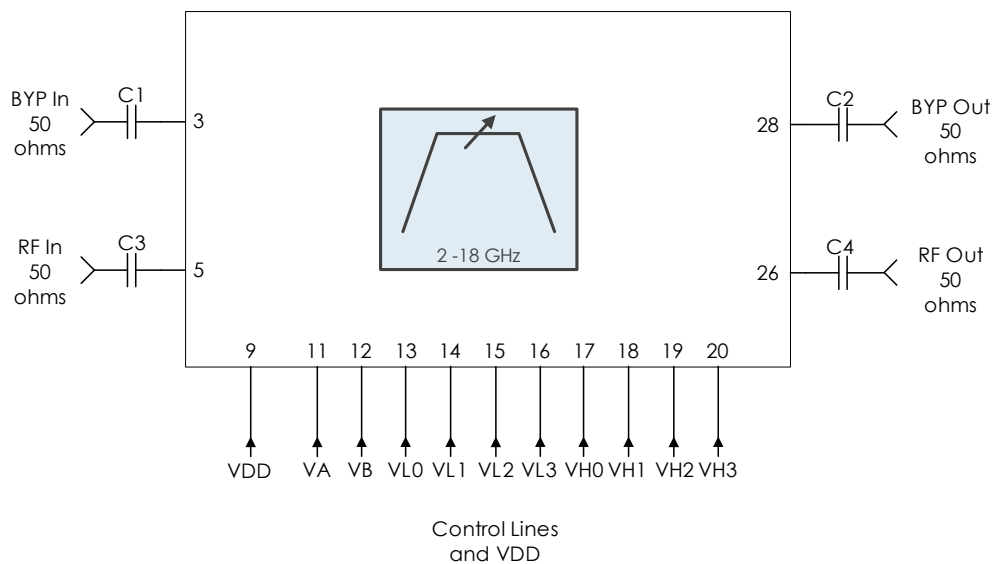


* Typical values shown for lowest tuned frequency (control bits 0000) or highest tuned frequency (control bits 1111)

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Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1-C4	0.1 μ F	0201BB104KW160	Passives Plus

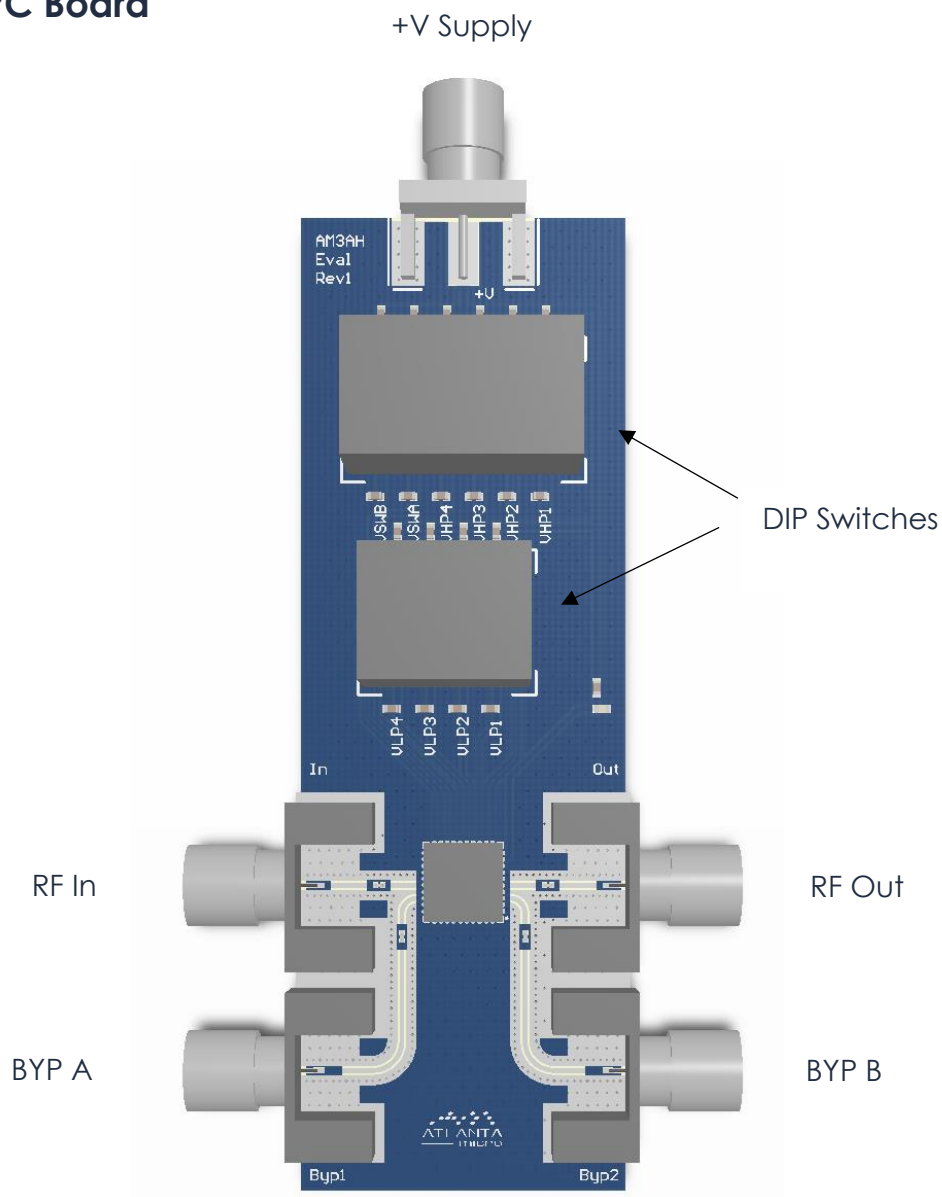
Notes:

1. DC blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance.
2. VDD and control lines filtered internally providing high frequency isolation.

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Evaluation PC Board



Related Parts

Part Number		Description		
AM3152	0.4 GHz to 8 GHz	Digitally Tunable Bandpass Filter		
AM3066	12 GHz to 26.5 GHz	Digitally Tunable Bandpass Filter		

Component Compliance Information

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Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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